

Combined Analysis: Texture-structure-microstructure-phase analysis of multi-phased ceramics and films using x-ray and neutron diffraction: examples of sinter-forged Bi2223-Bi2212, Melt Textured Growth Y-Ba-Cu-O and nano-Si

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**High-Tc
Superconductors**

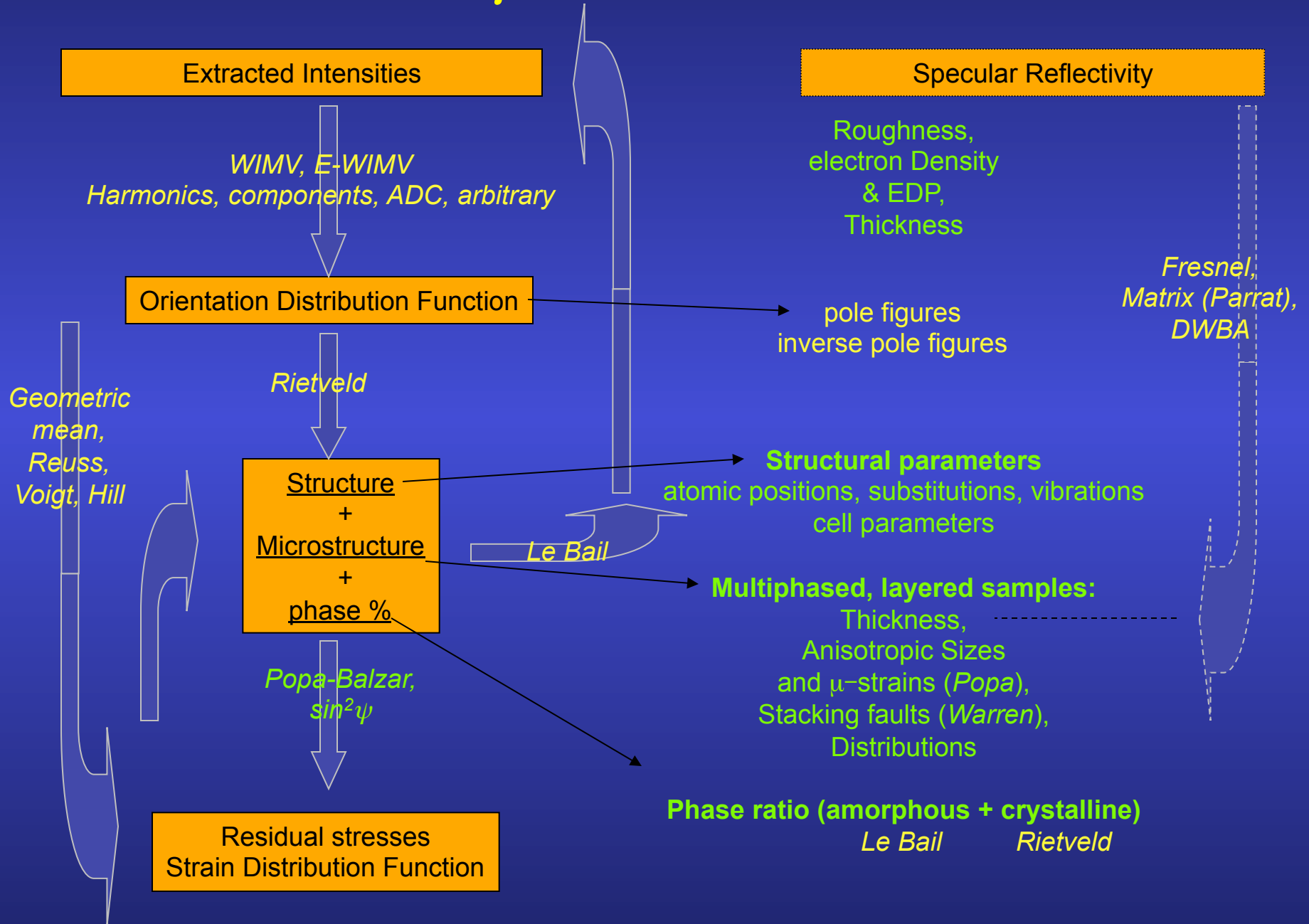
**nano-Si
thin films**

**PCT & PMN-PT
Ferroelectrics**



Electroceramics X, Toledo 2006

Implemented codes

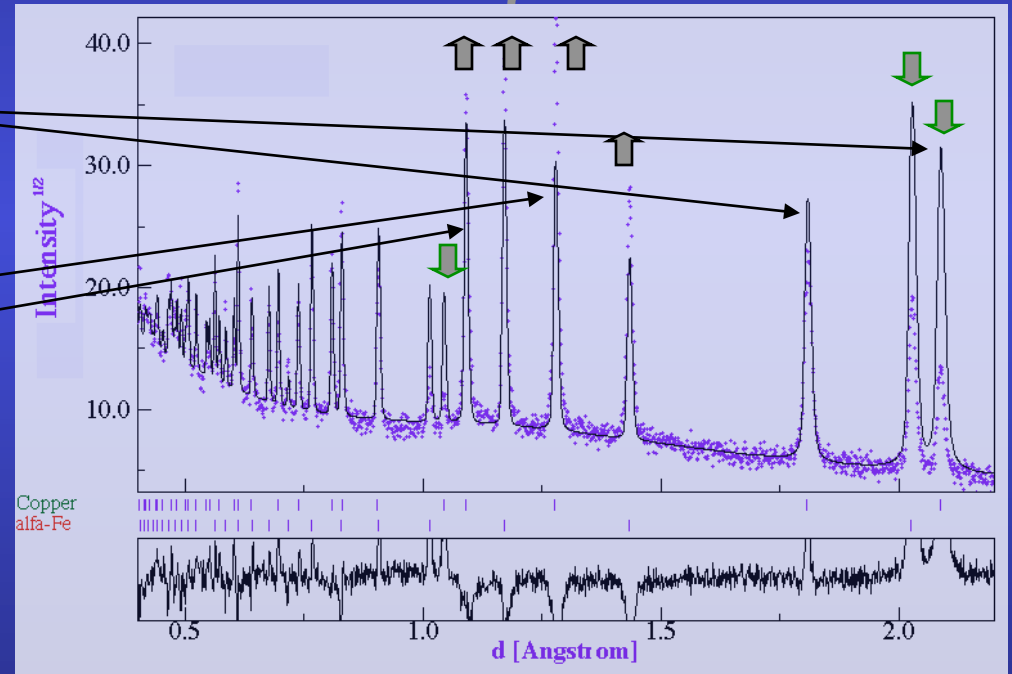
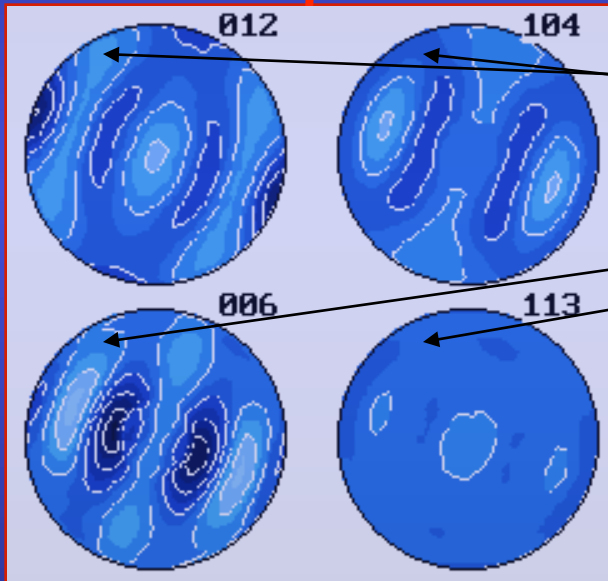


Texture from Spectra

Orientation Distribution Function (ODF)

From pole figures

From spectra



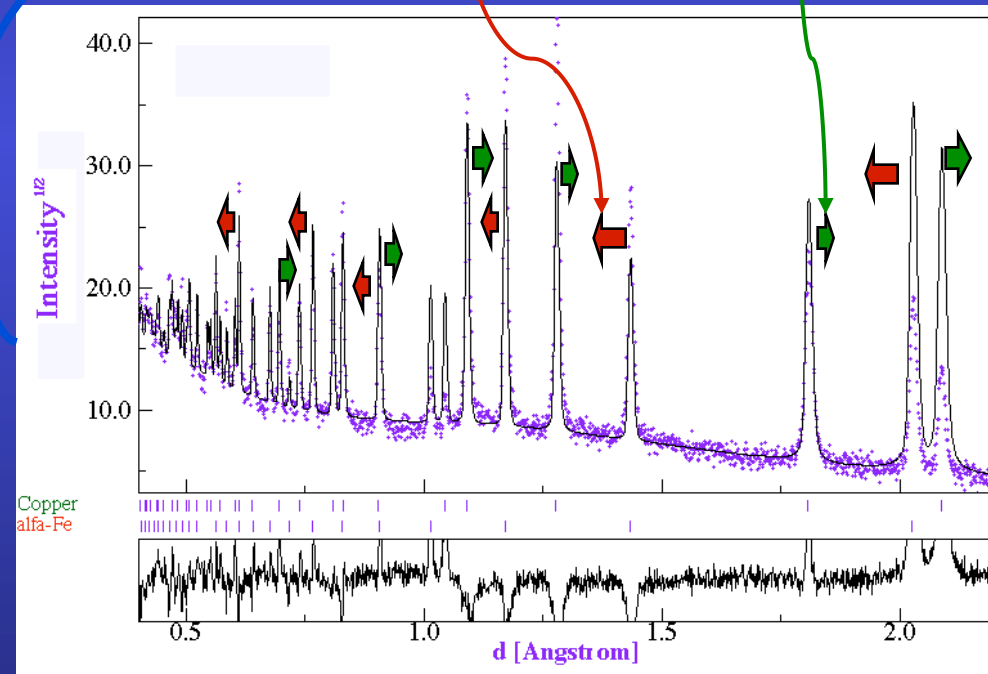
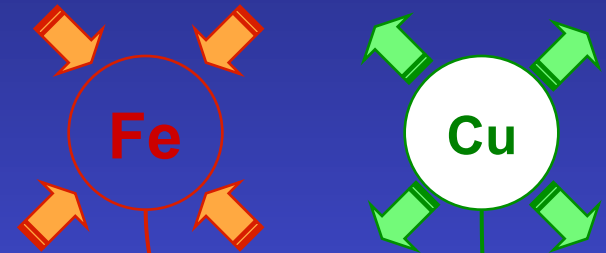
Residual Stresses and Rietveld

- Macro elastic strain tensor (I kind)
- Crystal anisotropic strains (II kind)

C

Macro and micro stresses

Applied macro stresses



Textured samples: Reuss, Voigt, Hill, Bulk geometric mean approaches

How it works (Combined)

$$I_i^{calc}(\chi, \phi) = \sum_{n=1}^{Nphases} S_n \sum_k L_k |F_{k;n}|^2 S(2\theta_i - 2\theta_{k;n}) P_{k;n}(\chi, \phi) A + bkg_i$$

Texture

$$P_k(\chi, \phi) = \int_{\varphi} f(g, \varphi) d\varphi$$

- from Generalized Spherical Harmonics:

$$P_k(\chi, \phi) = \sum_{l=0}^{\infty} \frac{1}{2l+1} \sum_{n=-l}^l k_l^n(\chi, \phi) \sum_{m=-l}^l C_l^{mn} k_n^{*m}(\Theta_k \phi_k)$$

$$f(g) = \sum_{l=0}^{\infty} \sum_{m,n=-l}^l C_l^{mn} T_l^{mn}(g)$$

- from the WIMV (left) iterative process or entropy maximisation (right):

$$f^{n+1}(g) = N_n \frac{f^n(g) f^0(g)}{\left(\prod_{h=1}^1 \prod_{m=1}^{M_h} P_h^n(\mathbf{y}) \right)^{\frac{1}{M_h}}}$$

$$f^{n+1}(g) = f^n(g) \prod_{m=1}^{M_h} \left(\frac{P_h(\mathbf{y})}{P_h^n(\mathbf{y})} \right)^{\frac{r_n}{M_h}}$$

Layering

$$C_{\chi}^{\text{top film}} = g_1 (1 - \exp(-\mu T g_2 / \cos \chi)) / (1 - \exp(-2\mu T / \sin \omega \cos \chi))$$

$$C_{\chi}^{\text{cov. layer}} = C_{\chi}^{\text{top film}} \left(\exp(-g_2 \sum \mu'_i T'_i / \cos \chi) \right) / \left(\exp(-2 \sum \mu'_i T'_i / \sin \omega \cos \chi) \right)$$

Popa anisotropic shapes & microstrains

$$\begin{aligned} \langle R_h \rangle &= R_0 + R_1 P_2^0(x) + R_2 P_2^1(x) \cos \varphi + R_3 P_2^1(x) \sin \varphi + R_4 P_2^2(x) \cos 2\varphi + R_5 P_2^2(x) \sin 2\varphi + \\ \langle \varepsilon_h^2 \rangle E_h^4 &= E_1 h^4 + E_2 k^4 + E_3 \ell^4 + 2E_4 h^2 k^2 + 2E_5 \ell^2 k^2 + 2E_6 h^2 \ell^2 + 4E_7 h^3 k + 4E_8 h^3 \ell + 4E_9 k^3 h + \\ &4E_{10} k^3 \ell + 4E_{11} \ell^3 h + 4E_{12} \ell^3 k + 4E_{13} h^2 k \ell + 4E_{14} k^2 h \ell + 4E_{15} \ell^2 k h \end{aligned}$$

Roughness and/or microabsorption

$$R^{\text{rough}}(q_z) = R(q_z) \exp(-q_{z,0} q_{z,1} \sigma^2) \quad \text{Low-angles (reflectivity)}$$

$$S_R = 1 - p \exp(-q) + p \exp\left(\frac{-q}{\sin \theta}\right) \quad \text{high-angle (Suortti)}$$

Specular reflectivity: $\mathbf{q}=(0,0,z)$

- Fresnel:

$$R(\mathbf{q}) = \left| \frac{q_z - \sqrt{q_z^2 - q_c^2 + \frac{32i\pi^2\beta}{\lambda^2}}}{q_z + \sqrt{q_z^2 - q_c^2 + \frac{32i\pi^2\beta}{\lambda^2}}} \right|^2 \delta q_x \delta q_y$$

- matrix:

$$R^{flat} = \frac{r_{0,1}^2 + r_{1,2}^2 + 2r_{0,1}r_{1,2} \cos 2k_{z,1}h}{1 + r_{0,1}^2 r_{1,2}^2 + 2r_{0,1}r_{1,2} \cos 2k_{z,1}h}$$

- Born approximation:

$$R(q_z) = r \cdot r^* = R_F(q_z) \left| \frac{1}{\rho_s} \int_{-\infty}^{+\infty} \frac{d\rho(z)}{dz} e^{iq_z z} dz \right|^2$$

Phase

$$W_{\Phi} = \frac{S_{\Phi} Z_{\Phi} M_{\Phi} V_{\Phi}}{\sum_{i=1}^{N_{\Phi}} S_i Z_i M_i V_i}$$

Strain-Stress

$$\boldsymbol{\varepsilon}(\mathbf{X}) = \boldsymbol{\varepsilon}^I + \boldsymbol{\varepsilon}^{II}(\mathbf{X}) + \boldsymbol{\varepsilon}^{III}(\mathbf{X})$$

$$\begin{aligned} \langle \boldsymbol{\varepsilon}_h(\mathbf{y}) \rangle_{V_d} &= \frac{1}{V_d} \int_{V_d} (\boldsymbol{\varepsilon}_{33}^I + \boldsymbol{\varepsilon}_{33}^{II} + \boldsymbol{\varepsilon}_{33}^{III}) dV \\ &= (\boldsymbol{\varepsilon}_{11}^I \cos^2 \phi + \boldsymbol{\varepsilon}_{12}^I \sin 2\phi + \boldsymbol{\varepsilon}_{22}^I \sin^2 \phi - \boldsymbol{\varepsilon}_{33}^I) \sin^2 \psi + \boldsymbol{\varepsilon}_{33}^I + \\ &\quad (\boldsymbol{\varepsilon}_{13}^I \cos \phi + \boldsymbol{\varepsilon}_{23}^I \sin \phi) \sin 2\psi + \frac{1}{V_d} \int_{V_d} (\boldsymbol{\varepsilon}_{33}^{IIe} + \boldsymbol{\varepsilon}_{33}^{IIa} + \boldsymbol{\varepsilon}_{33}^{IIpi}) dV \\ &= \frac{\langle d(hkl, \phi, \psi) \rangle_{V_d} - d_0(hkl)}{d_0(hkl)} \end{aligned}$$

Isotropic samples:

Tri-, bi-, uni-axial stress states

Textured samples:

Tri-, bi-, uni- stress states
+ ODF + SDF + model

$$\begin{aligned} \langle E(\mathbf{g}) \rangle_{V_d} &= \frac{1}{V_d} \int_{V_d} E^{SC}(\mathbf{g}) f(\mathbf{g}) d\mathbf{g} \quad \Rightarrow \quad C_{ijkl}^M \neq \left(S_{ijkl}^M \right)^{-1} \\ &= \left(\prod_{V_d} E^{SC}(\mathbf{g}) f(\mathbf{g}) d\mathbf{g} \right)^{\frac{1}{V_d}} \quad \Rightarrow \quad C_{ijkl}^M = \left(S_{ijkl}^M \right)^{-1} \end{aligned}$$

Reuss, Voigt, Hill

Geometric mean, VPSC

Minimum experimental requirements

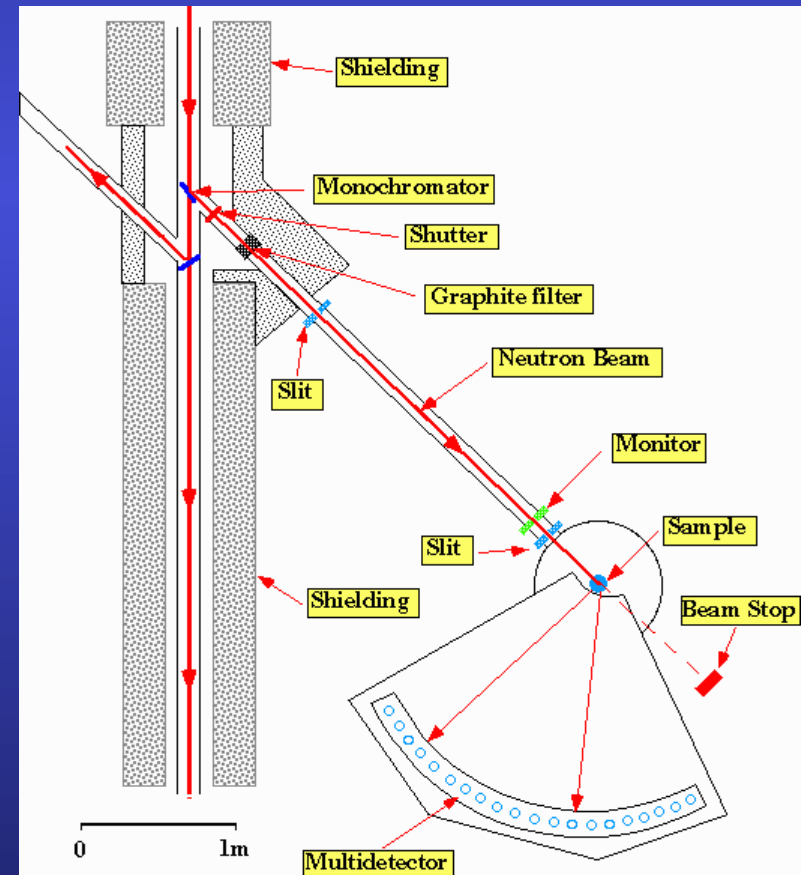
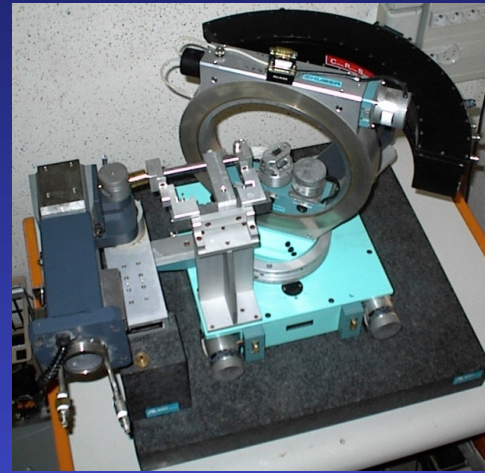
1D or 2D Detector + 4-circle diffractometer
(X-rays and neutrons)
CRISMAT, ILL

+

~1000 experiments (2θ diagrams)
in as many sample orientations

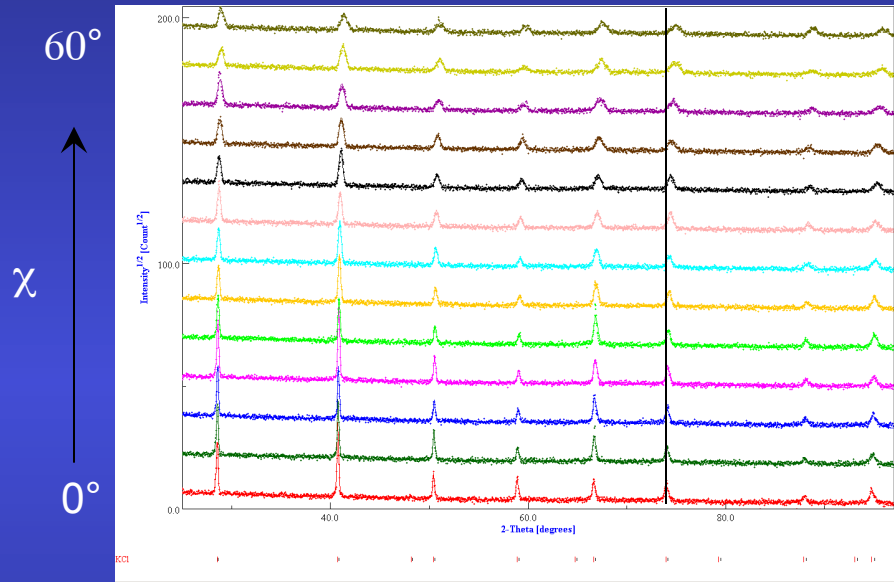
+

Instrument calibration
(peaks widths and shapes,
misalignments, defocusing ...)

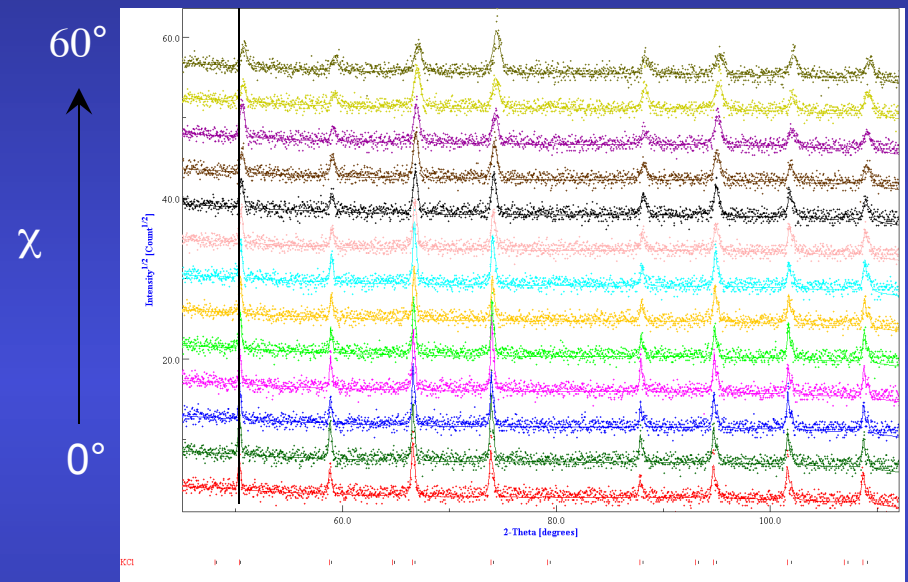


Calibration

$\omega = 20^\circ$



$\omega = 40^\circ$



KCl, LaB₆ ...



FWHM (ω , χ , 2θ ...)
2 θ shift
gaussianity
asymmetry
misalignments ...

Methodology implementation

L. Lutterotti, Trento

User friendly interface

The screenshot shows the MAUD software interface. At the top, there's a 'TreeTable' window with columns for Name, Value, Error, and Status. Below it is the 'Refinement wizard' with several options under 'Refine' and 'Special'. On the left, there's a 'Pole Figure plot' section with 'Reconstructed' and 'Experimental' buttons. At the bottom left, there's a 3D visualization of a crystal structure.

Name	Value	Error	Status
_atom_site_aniso_U_12	0.0	0.0	Fixed
_atom_site_aniso_U_13	0.0	0.0	Fixed
_atom_site_aniso_U_22	0.0	0.0	Refined
_atom_site_aniso_U_23	0.0	0.0	Equal to
_atom_site_aniso_U_33	0.0	0.0	Refined
Copper	-	-	-
_cell_length_a	3.614566...	0.00002	Refined

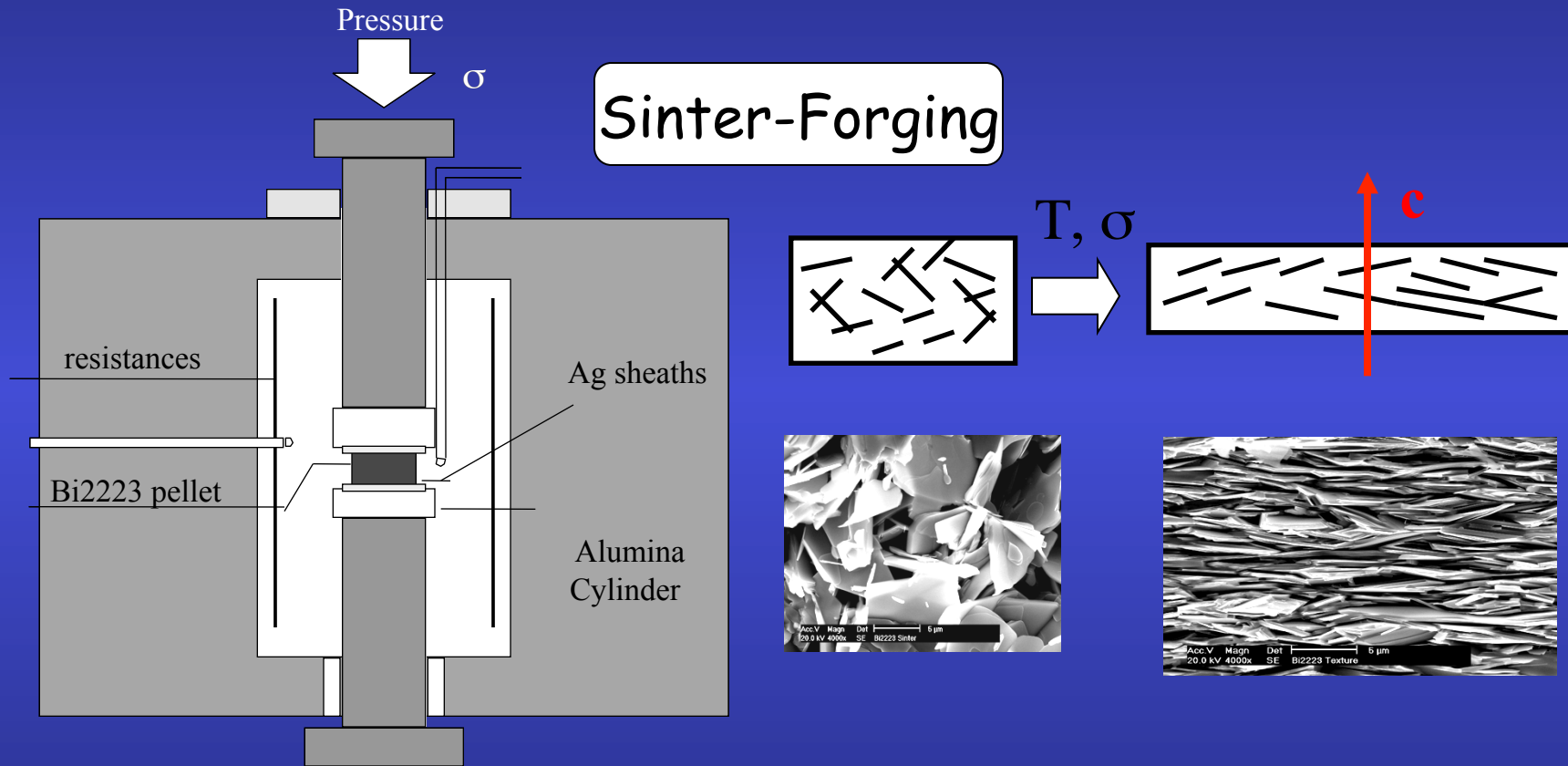
This screenshot shows the MAUD software interface with the 'Microstructure' dialog box open. The dialog box has several sections: 'Line Broadening' with a dropdown menu showing 'Delf' selected, 'Size-Strain model' set to 'Popa LB', 'Antiphase boundary model' set to 'none abm', and 'Planar defects model' set to 'none pd'. There are also 'Options' buttons for each section. Below the dialog box, there's a 3D visualization of a crystal structure and two XRD patterns. The bottom pattern shows a full scan from 50.0 to 150.0 degrees 2-Theta, and the top pattern is a zoomed-in view from 130.0 to 140.0 degrees 2-Theta.

Java codes
Java web start updates

ation computation
or sample: CPD-Y203
ures: 14267.7133202
putation

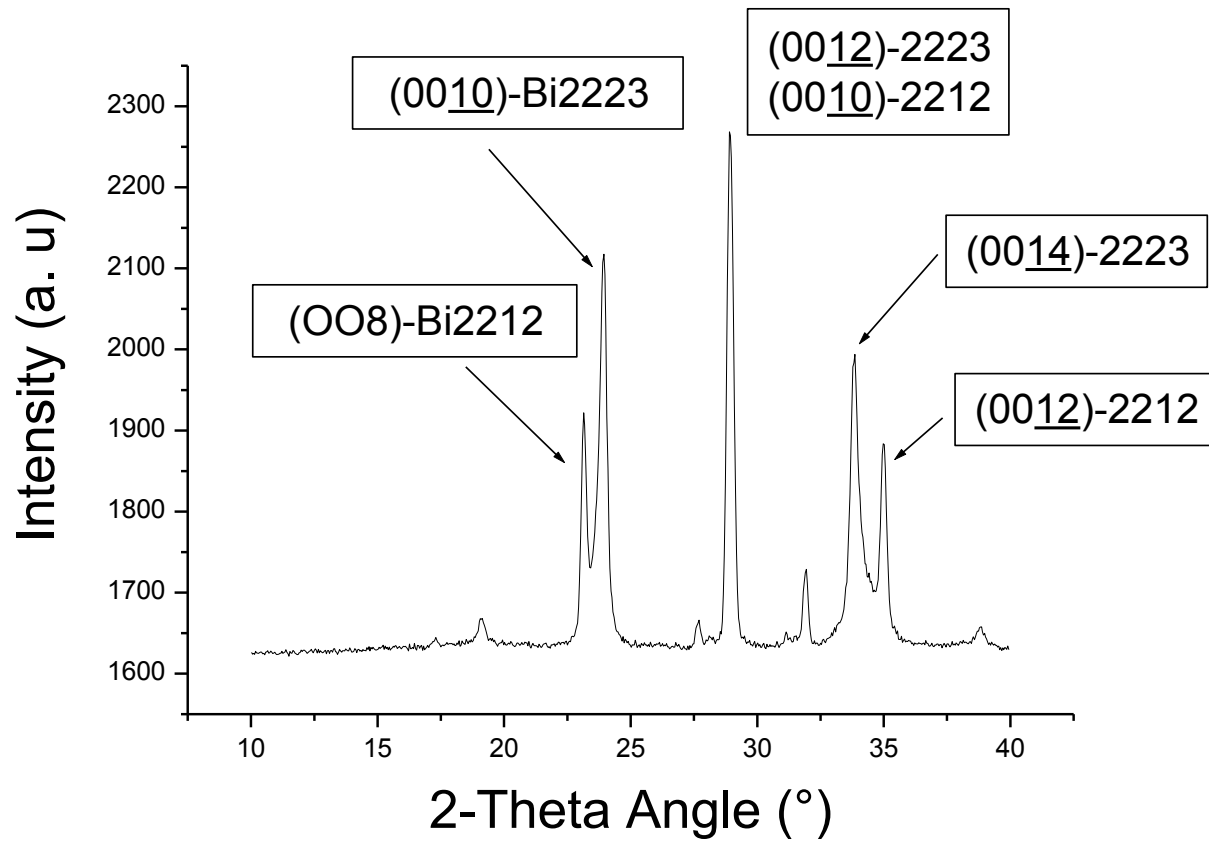
Bi2223 compounds

E. Guilmeau, CRISMAT

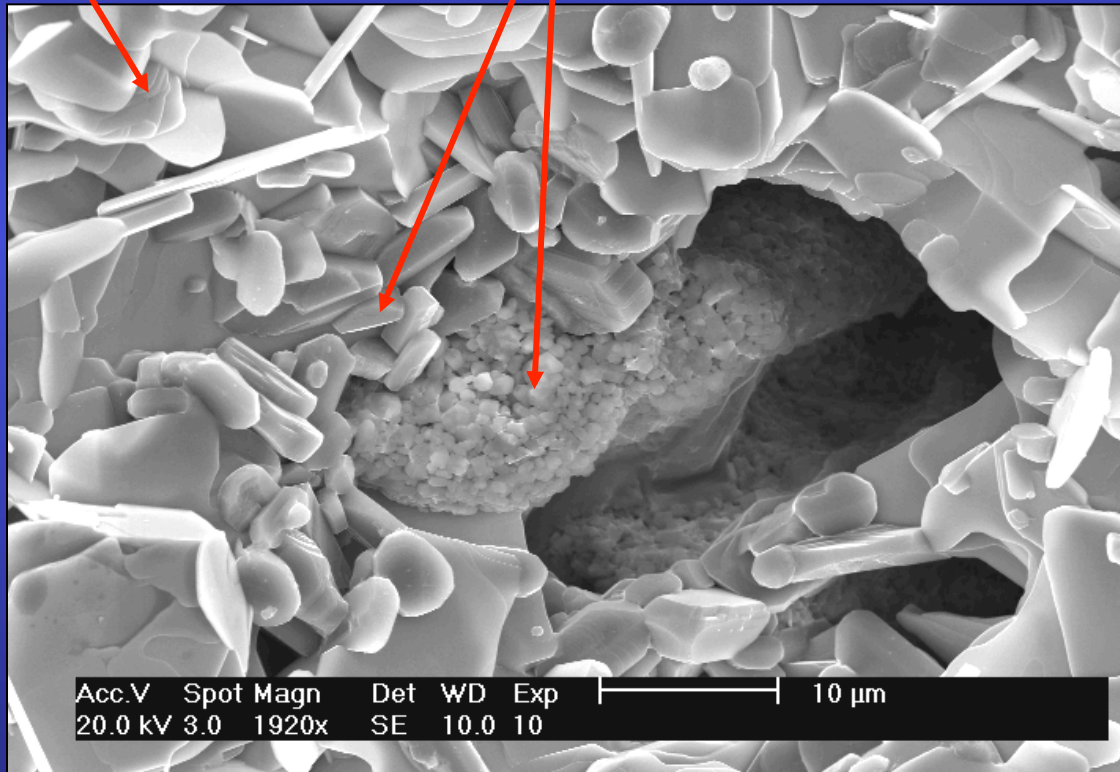


Grain alignment \Rightarrow \nearrow J_c

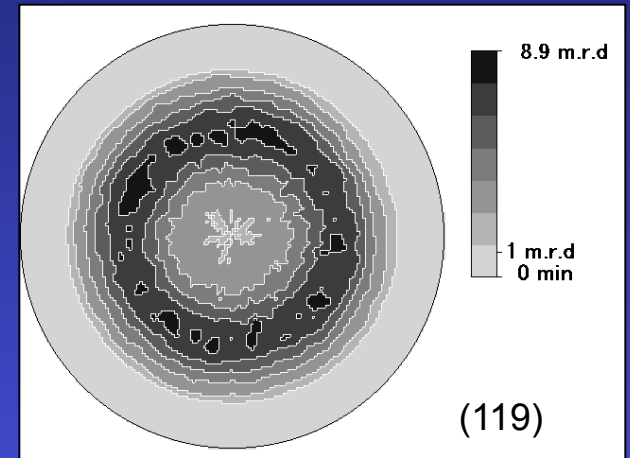
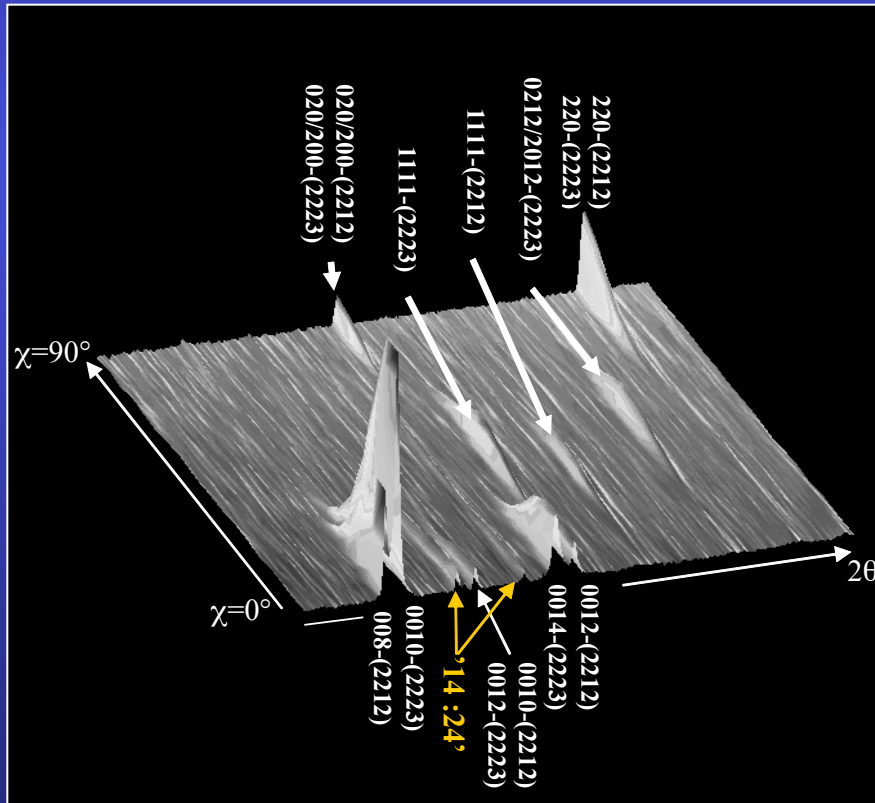
(00ℓ) Texture



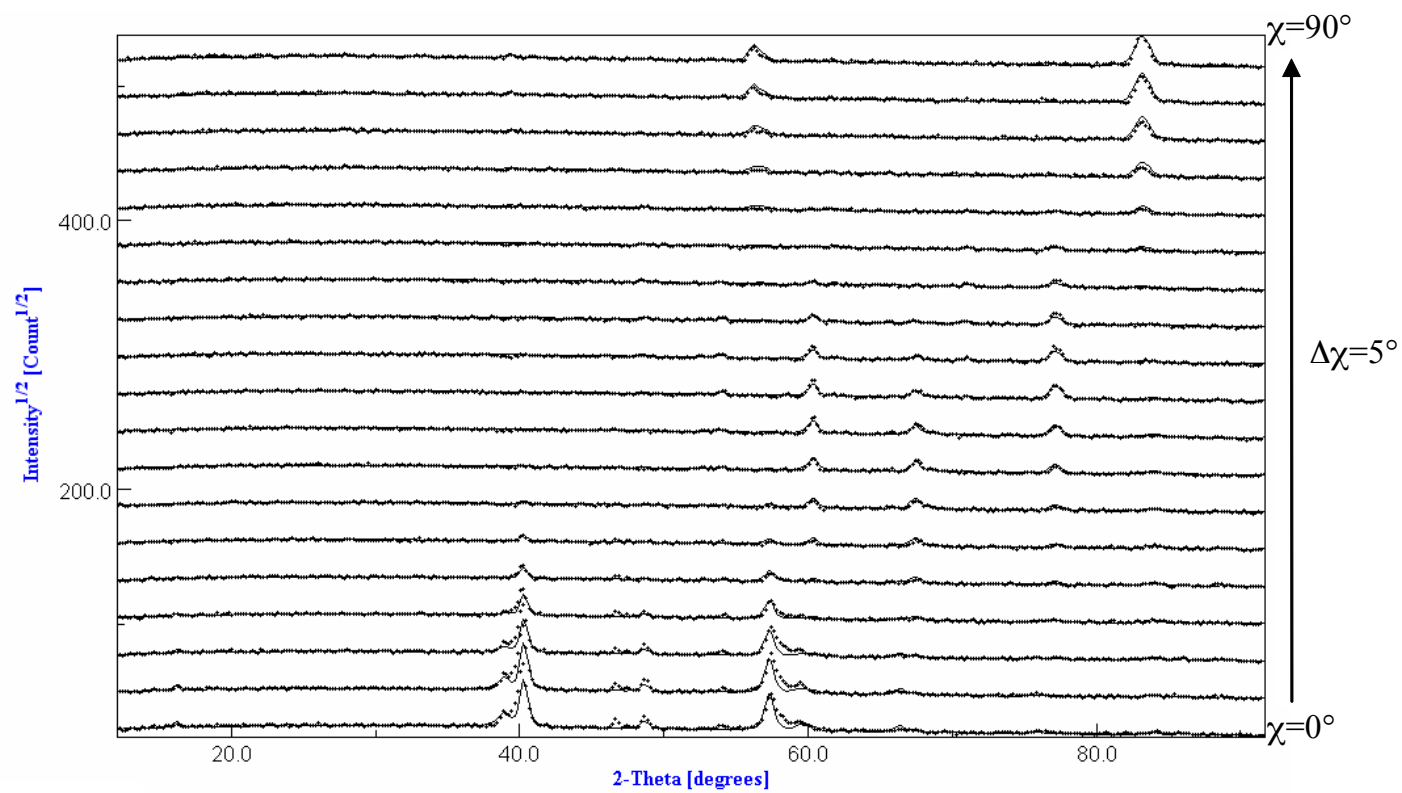
Bi2212 + Secondary phases \longrightarrow Bi2223



Combined Analysis



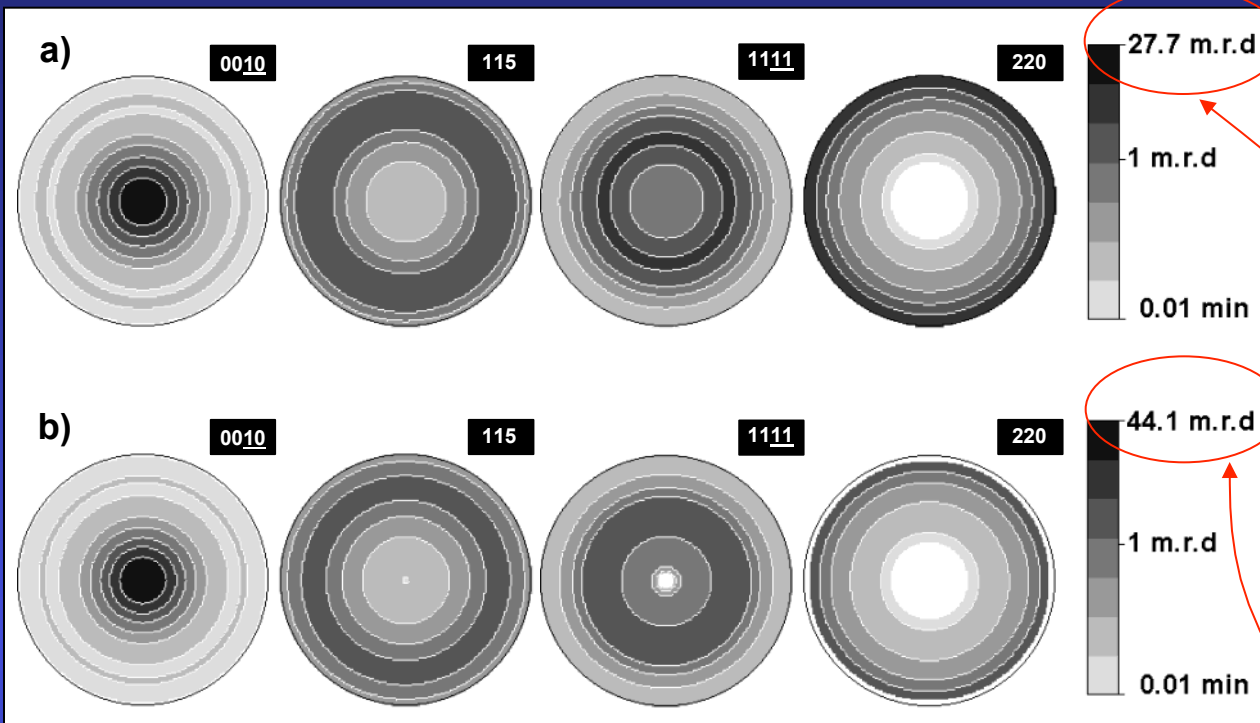
- Neutrons
- Sample: $\sim 70 \text{ mm}^3$
- 2θ patterns for $\chi=0^\circ$ to 90°
- No φ rotation (fibre texture).



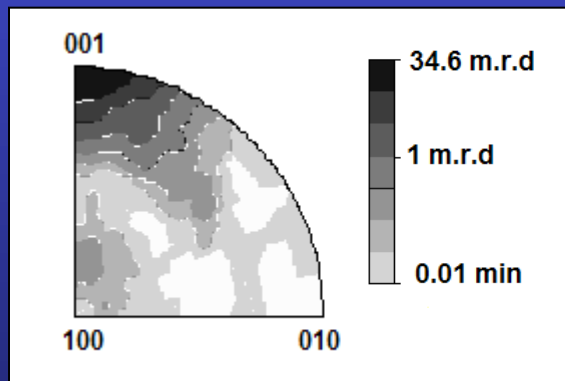
2223
2212



$R_w = 9.12$
 $RP = 16.24$



Logarithmic density scale, equal area projection



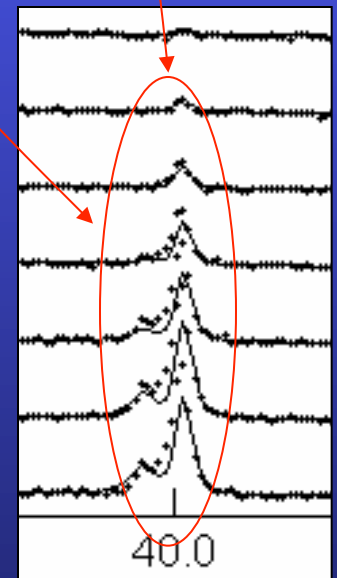
Logarithmic density scale, equal area projection

Stacking faults and/or intergrowth on the c-axis
 → New periodicities and peaks characterized with intermediate c parameters.

However, no algorithm is included to solve intergrowths in the combined approach.

Recalculated (WIMV)

Extracted (Le Bail)



Effect of the sinter-forging treatment on the texture development, crystal growth, transport properties

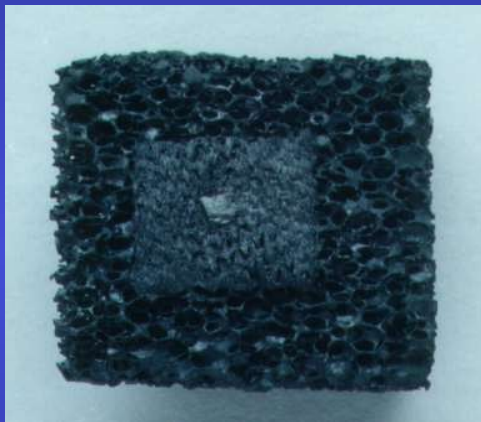
Sinter-forging dwell time (h)	Orientation Distribution Max (m.r.d.)		% Bi2223	Cell parameters (Å)		Crystallite size Bi2223 (nm)	Rb (%)	Rw (%)	Rexp (%)	RP0 (%)	RP1 (%)	J_c (A/cm ²)
	Bi2212	Bi2223		Bi2223	Bi2212							
20	21.8	20.7	59.9±1.3	a=5.419(3) b=5.391(3) c=37.168(3)	a=5.414(3) b=5.393(3) c=30.800(3)	205±7	7.56	11.1	4.55	17.74	10.56	12500
50	24.1	24.4	72.9±2.9	a=5.419(3) b=5.408(3) c=37.192(3)	a=5.416(3) b=5.396(3) c=30.806(3)	273±10	7.54	11.37	4.58	17.05	11.04	15000
100	31.5	25.2	84.4±4.6	a=5.410(3) b=5.405(3) c=37.144(3)	a=5.412(3) b=5.403(3) c=30.752(3)	303±10	5.4	8.04	3.69	13.54	9.31	19000
150	65.4	27.2	87.0±4.1	a=5.417(3) b=5.403(3) c=37.199(3)	a=5.413(3) b=5.407(3) c=30.792(3)	383±13	6.13	9.12	4.8	16.24	12.25	20000



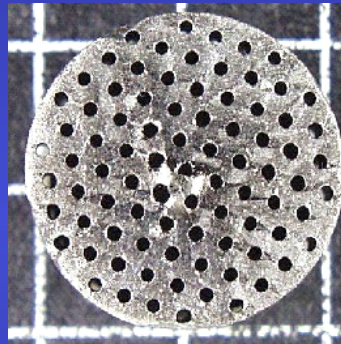
$YBa_2Cu_3O_{7+d}$ compounds

D. Grossin, S. Meslin, CRISMAT

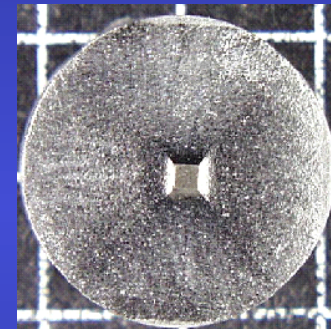
MTG, TSMTG, infiltrated/perforated and foams



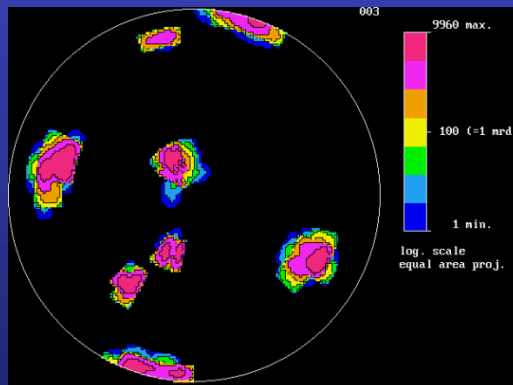
Infiltrated Polyurethane
foam, annealed



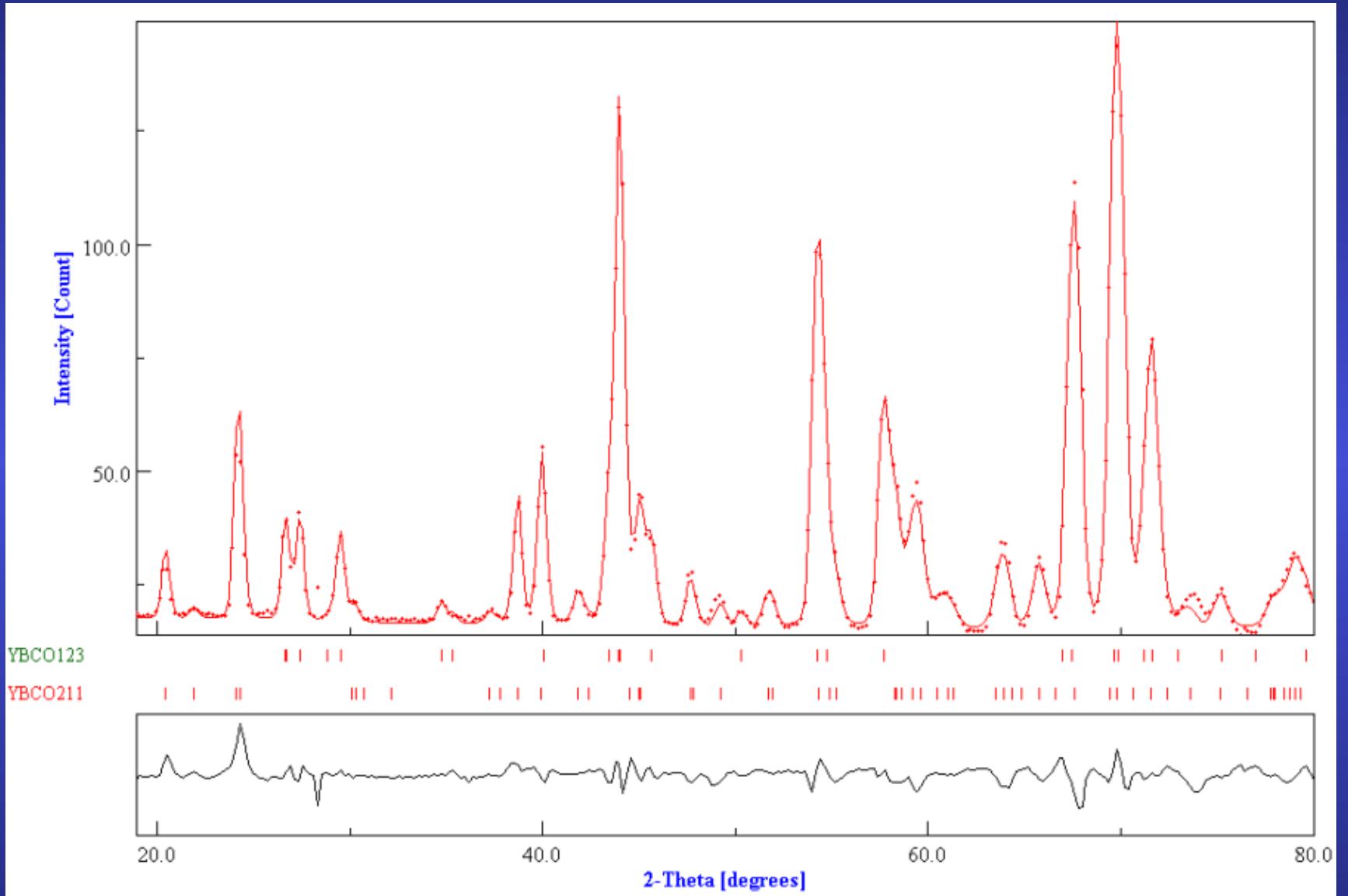
Perforated



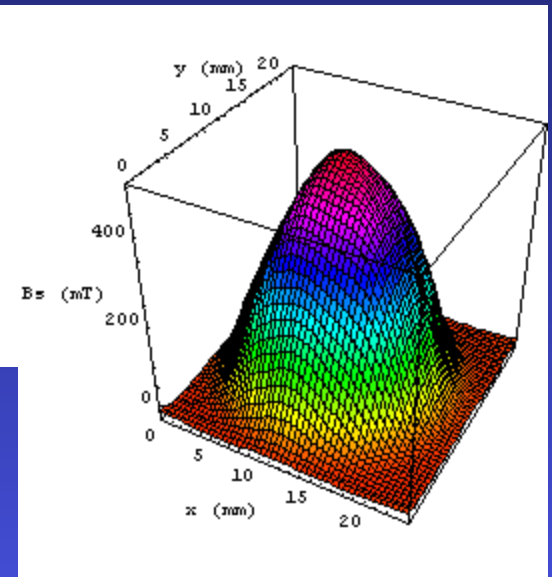
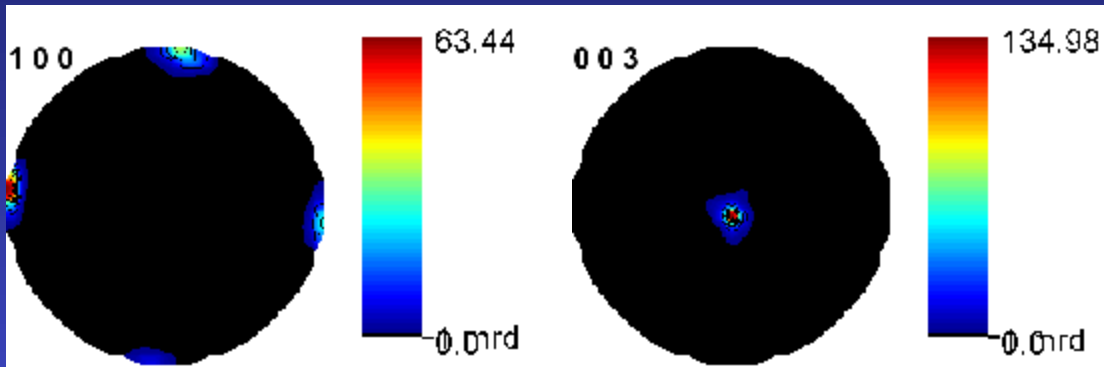
TSMTG



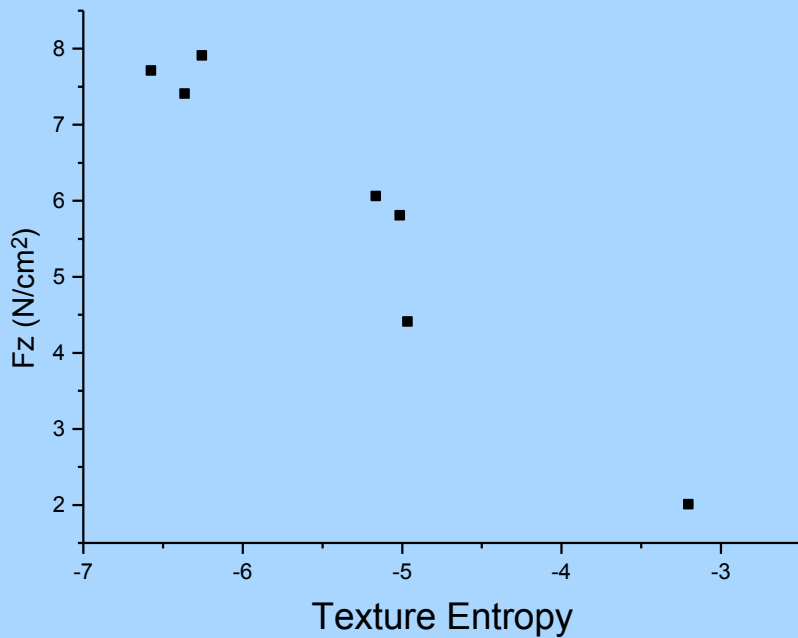
Mixtures of $YBa_2Cu_3O_7$ superconducting and Y_2BaCuO_5 insulating (needed for vortex pinning)



$R_w = 5.43\%$, $R_{\text{Bragg}} = 19.71\%$

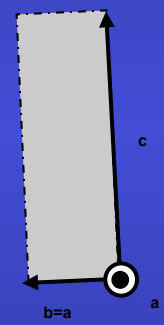
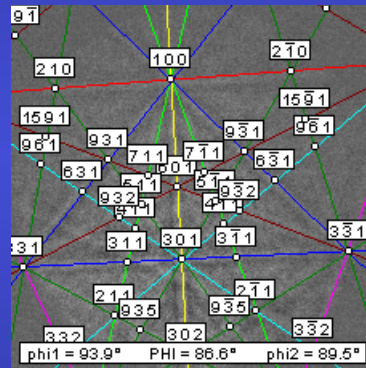
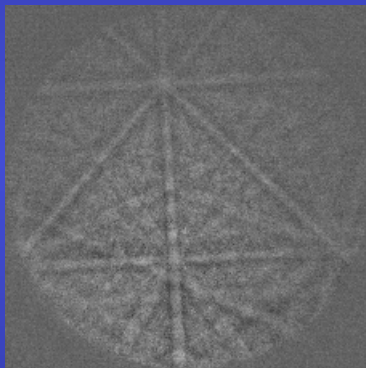
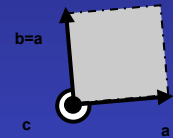
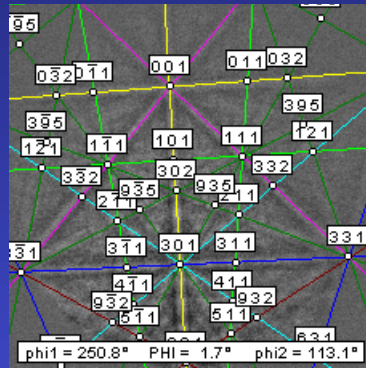
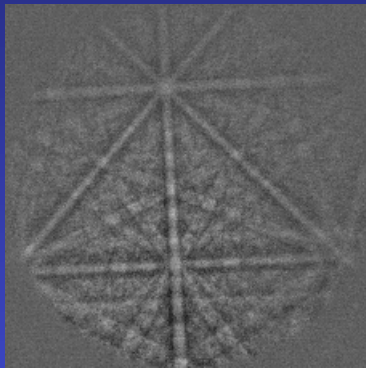


Neutron pole figures (D1B-ILL) and trapped flux



Levitation force

Models ?

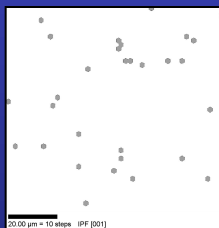


Scan 01
(1.42% 90-misorientation)

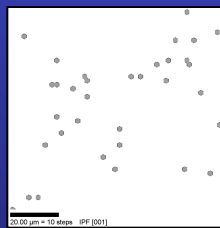
Scan 02
(1.66% 90-misorientation)

Scan 03
(1.59% 90-misorientation)

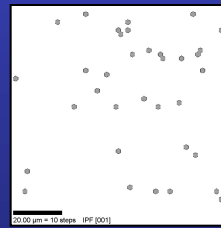
Scan SUM



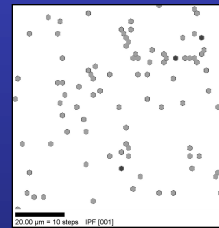
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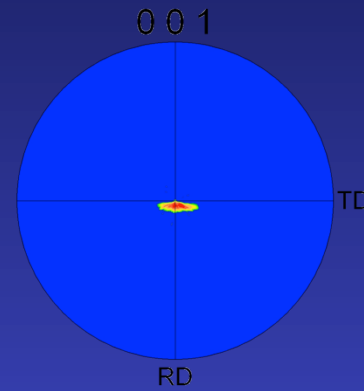
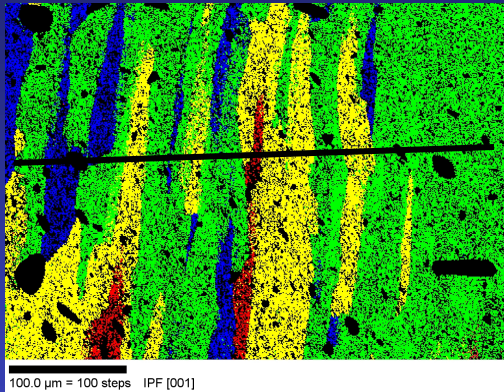


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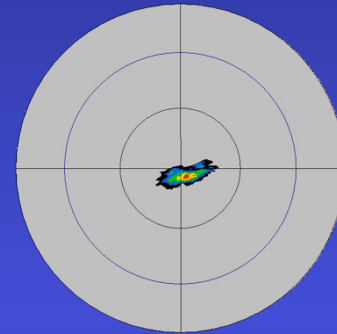


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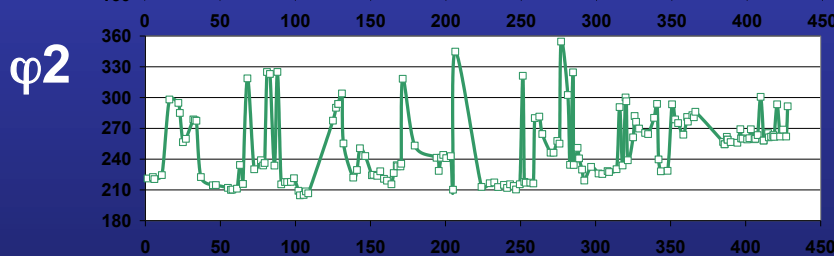
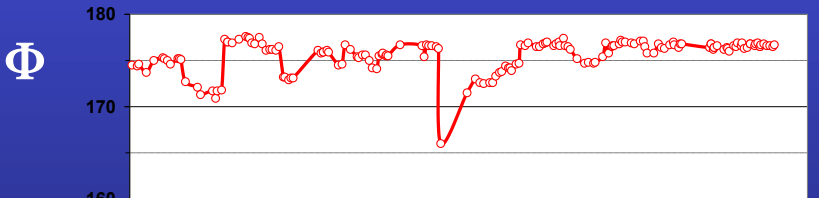
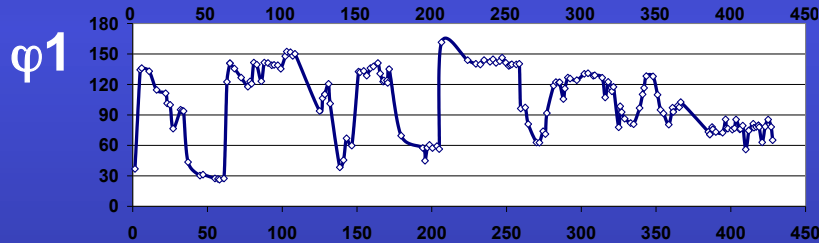
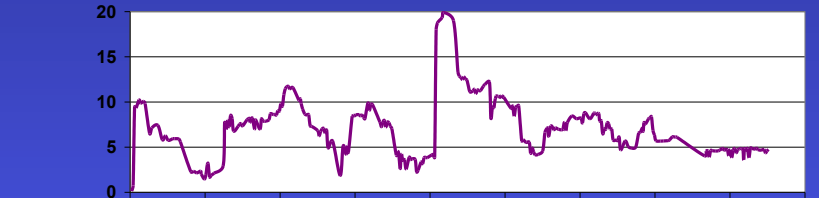


EBSD {001}:
max = 1600 mrd



ND {001}: max =
128 mrd

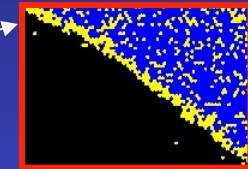
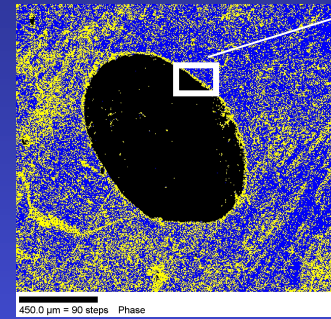
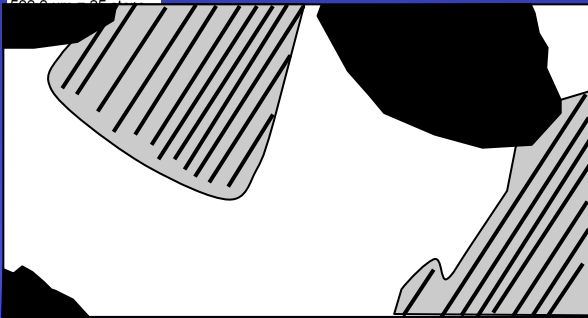
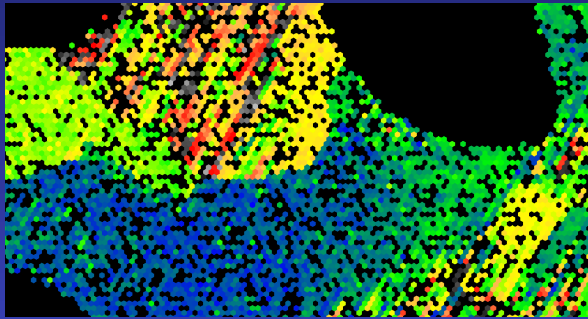
EBSD rescaling ?




- Small g variation inside on twinned domain: large J_c 's

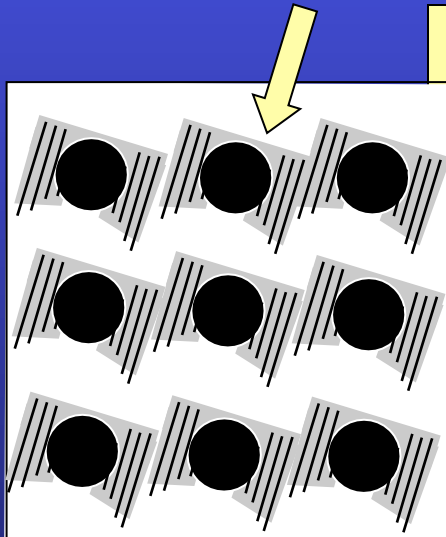
- large φ_1 variations at twin boundaries: Twist boundaries

- but small Φ variations: small tilt boundaries: large J_c 's too



	Phase	Fraction
	YBCO 123	0.58
	YBCO 211	0.42

Crystal growth direction



- large and small subdomains misorientation are observed, introduced by perforation
- small dg accessible in pseudo-symmetry

Si nanocrystalline thin films

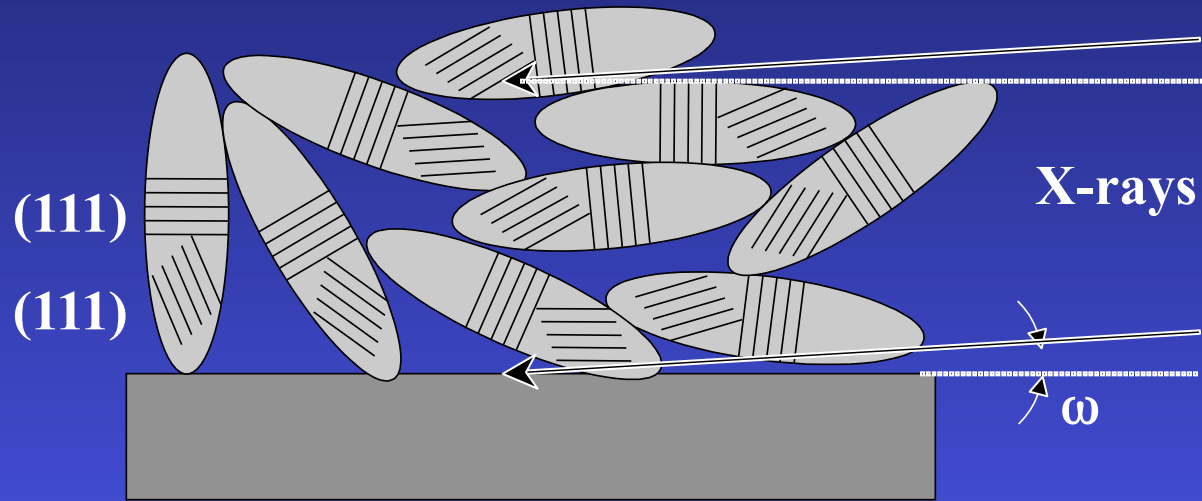
M. Morales, SIFCOM-Caen

Silicon thin films deposition by reactive magnetron sputtering:

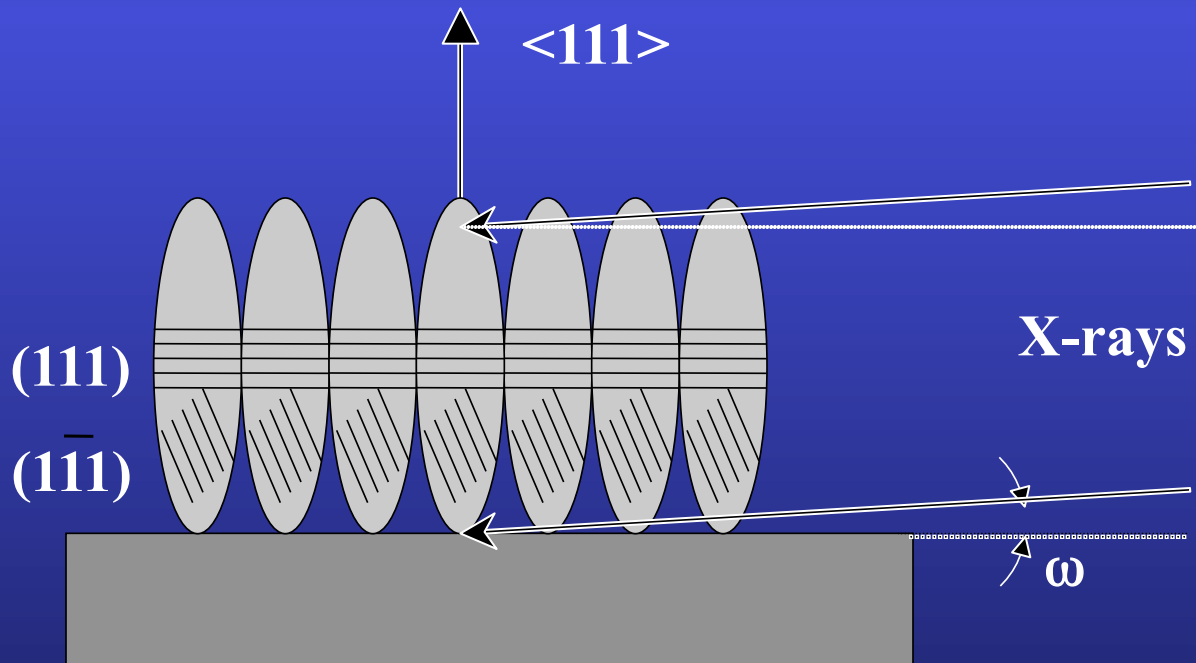
- ⇒ power density $2\text{W}/\text{cm}^2$
- ⇒ total pressure: $p_{\text{total}} = 10^{-1}$ Torr
- ⇒ plasma mixture: H_2 / Ar , $p_{\text{H}_2} / p_{\text{total}} = 80\%$
- ⇒ temperature: 200°C
- ⇒ substrates: amorphous SiO_2 (a-SiO_2)
(100)-Si single-crystals
- ⇒ target-substrate distance (d)
 - a-SiO_2 substrates: $d = 4, 6, 7, 8, 10, 12$ cm
films A, B, C, D, E, F
 - (100)-Si: $d = 6, 12$ cm
films G, H

Aim: quantum confinement, photoluminescence properties

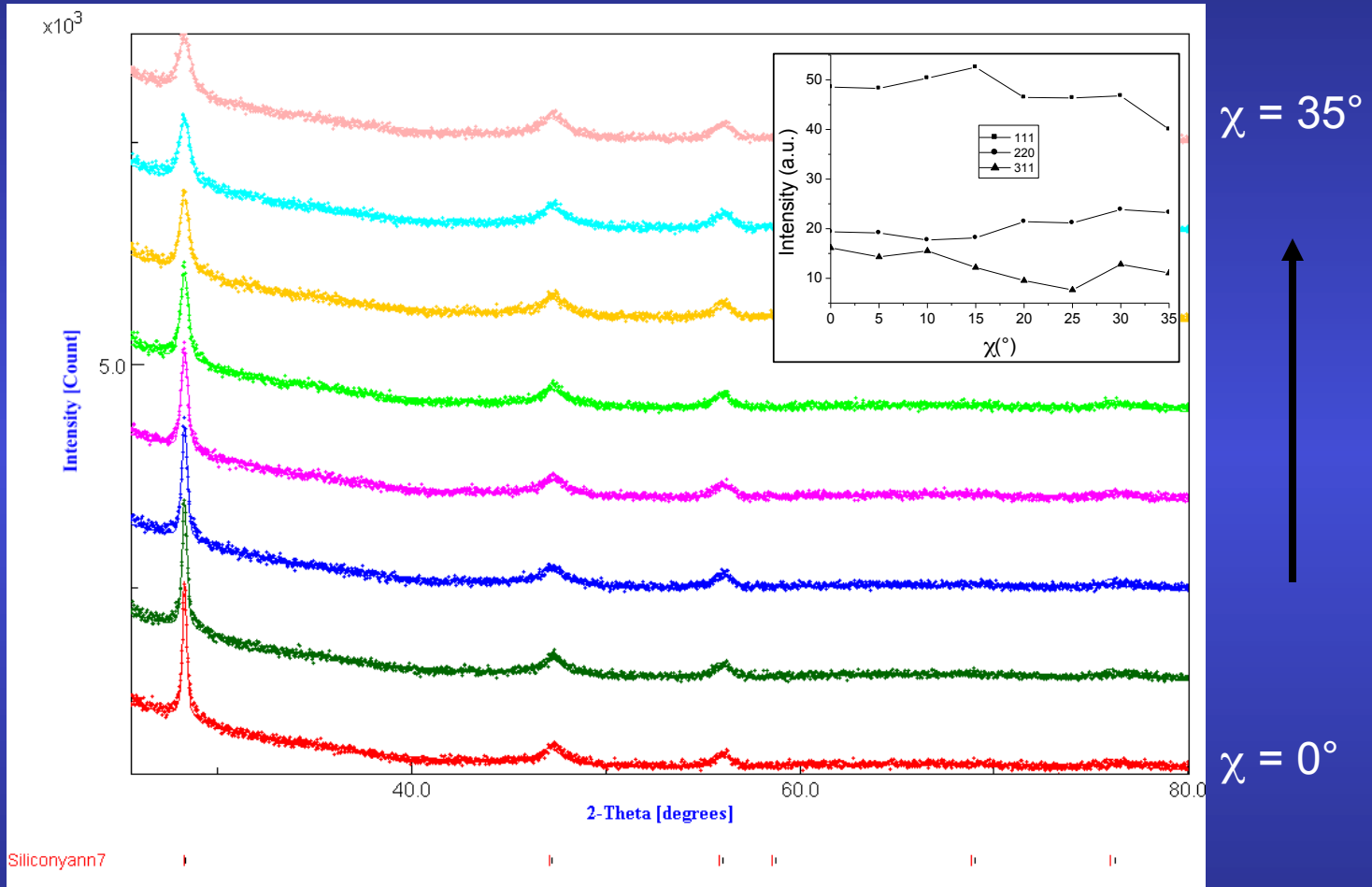
Isotropic



Textured



Typical refinement

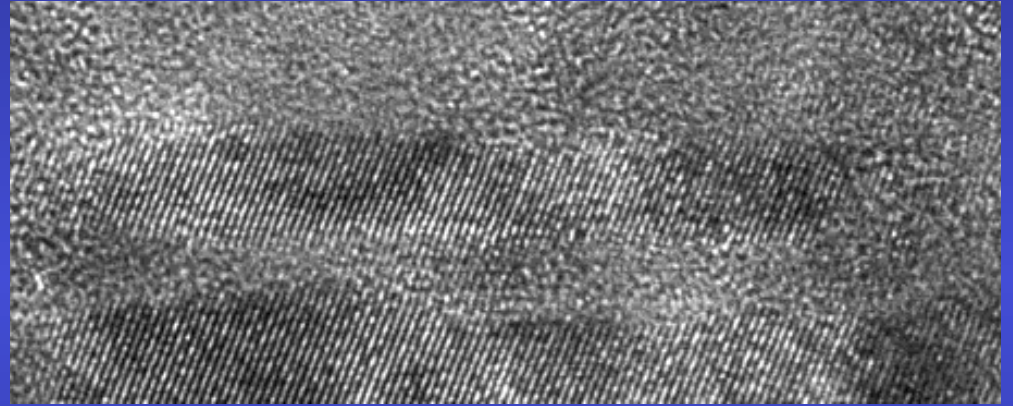
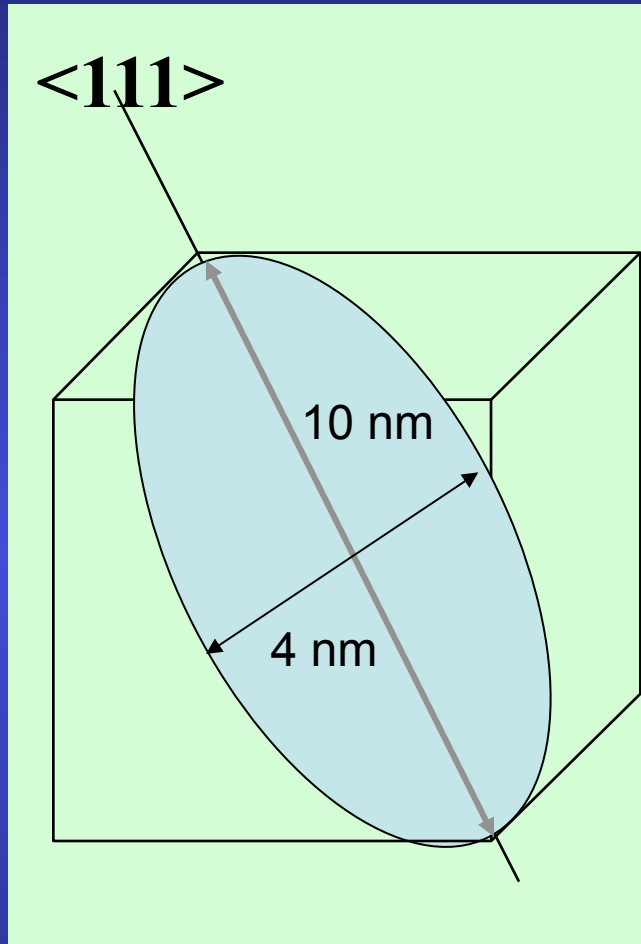


broad, anisotropic diffracted lines, textured samples

Refinement Results

Sample	d (cm)	a (Å)	RX thickness (nm)	Anisotropic sizes (Å)			Texture parameters			Reliability factors (%)			
				<111>	<220>	<311>	Maximum (m.r.d.)	minimum (m.r.d.)	Texture index F ² (m.r.d ²)	RP ₀	R _w	R _B	R _{exp}
A	4	5.4466 (3)	—	94	20	27	1.95	0.4	1.12	1.72	4.0	3.7	3.5
B	6	5.4439 (2)	711 (50)	101	20	22	1.39	0.79	1.01	0.71	4.9	4.3	4.2
C	7	5.4346 (4)	519 (60)	99	40	52	1.72	0.66	1.05	0.78	4.3	4.0	3.9
D	8	5.4461 (2)	1447 (66)	100	22	33	1.57	0.63	1.04	0.90	5.5	4.6	4.5
E	10	5.4462 (2)	1360 (80)	98	20	25	1.22	0.82	1.01	0.56	5.0	3.9	4.0
F	12	5.4452 (3)	1110 (57)	85	22	26	1.59	0.45	1.05	1.08	4.2	3.5	3.7
G	6	5.4387 (3)	1307 (50)	89	22	28	1.84	0.71	1.01	1.57	5.2	4.7	4.2
H	12	5.4434 (2)	1214 (18)	88	22	24	2.77	0.50	1.12	2.97	5.0	4.5	4.3

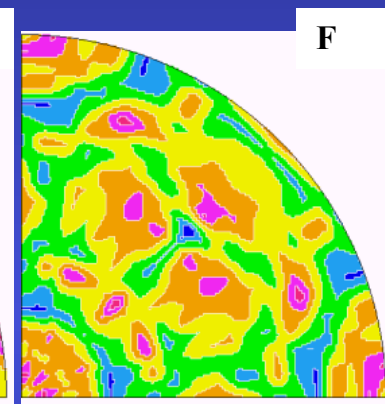
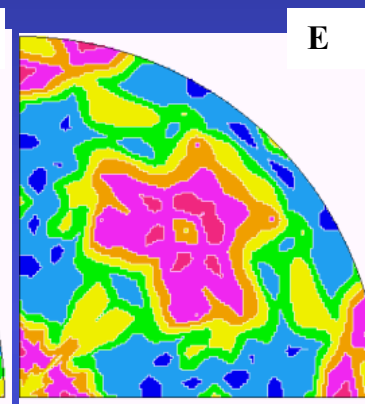
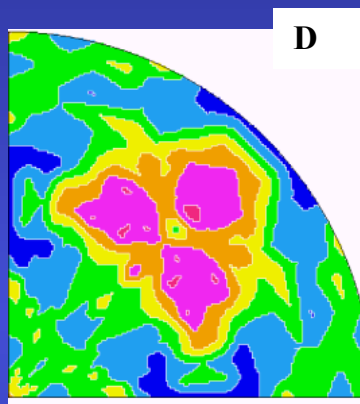
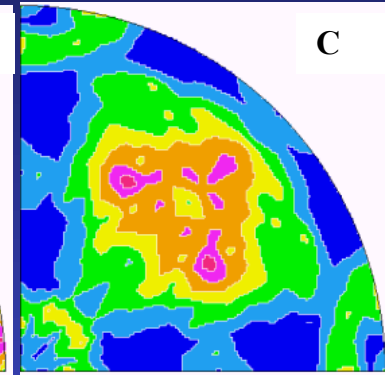
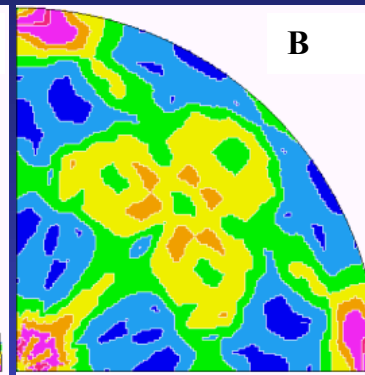
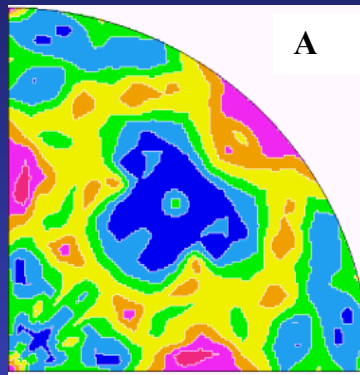
Mean anisotropic shape



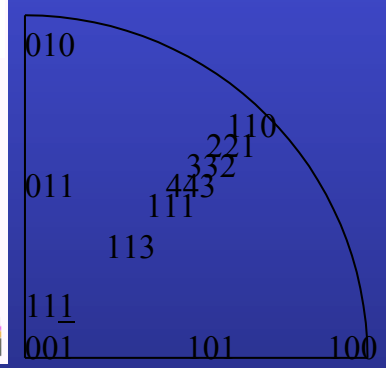
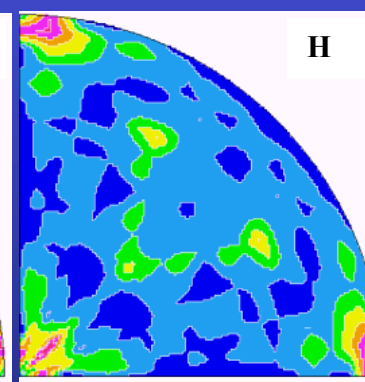
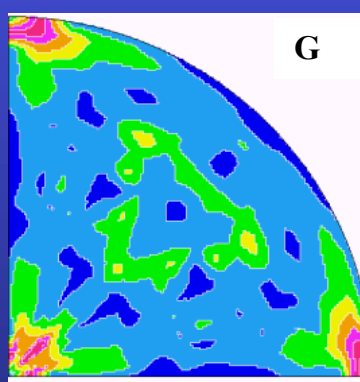
Schematic of the mean crystallite shape for Sample D represented in a cubic cell, as refined using the Popa approach and exhibiting a strong elongation along $\langle 111 \rangle$, and TEM image

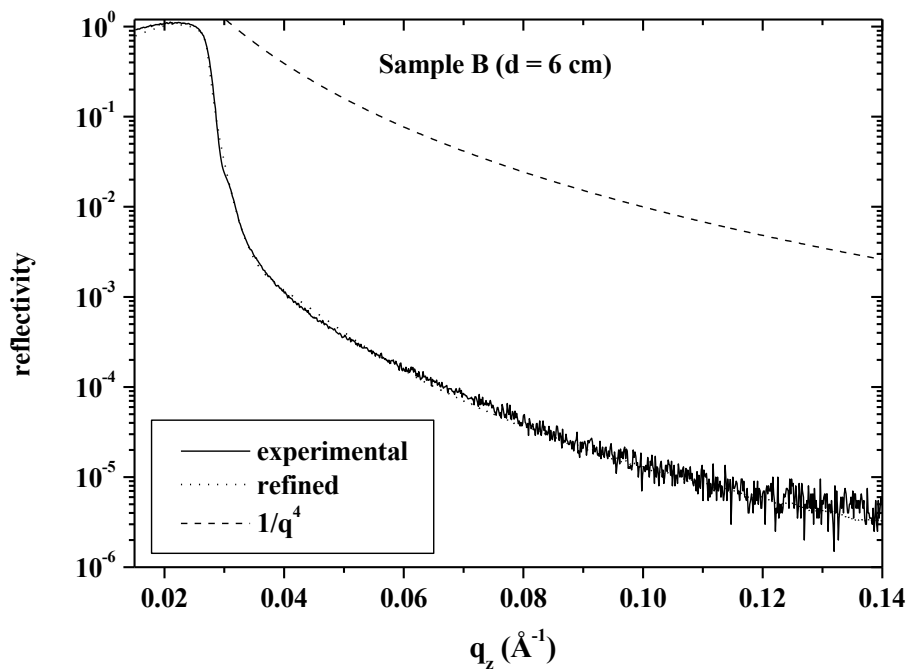
001 Inverse Pole Figures

a-SiO₂



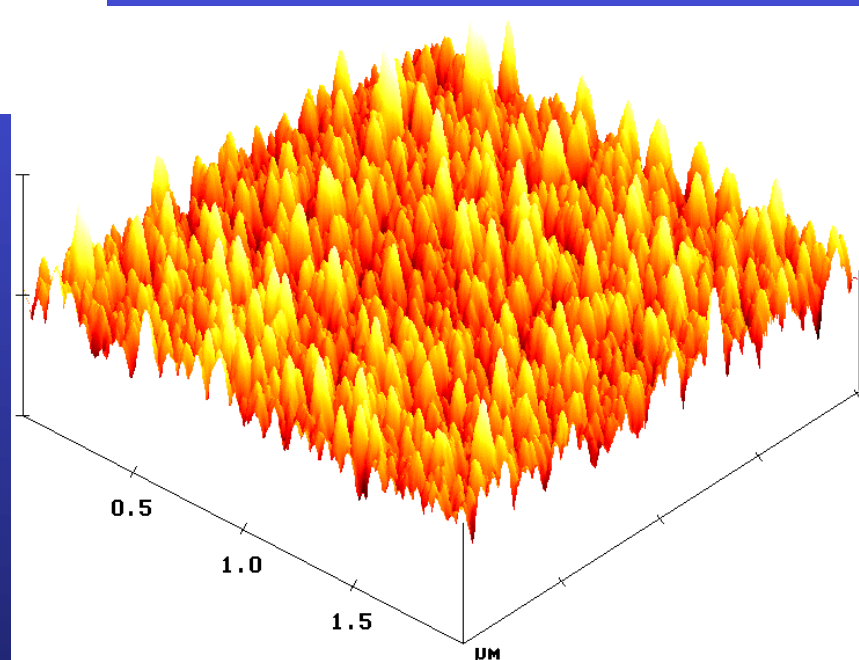
(100)-Si

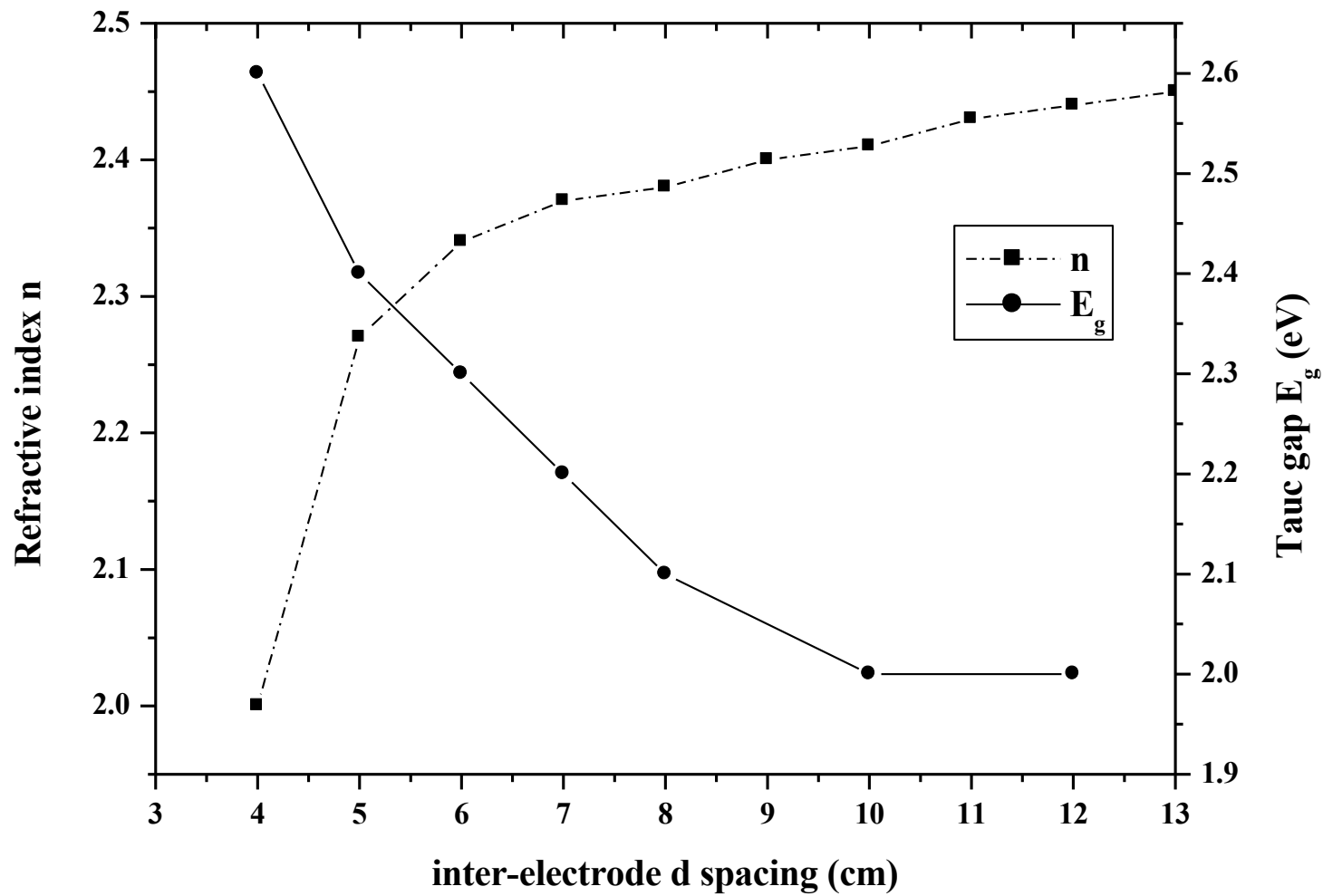




XRR:
Roughness
governed

AFM:
homogeneous
roughness





Conclusions

- a) Texture affects phase ratio and structure determination
- b) Microstructure (crystallite size) affects texture (go to a)
- c) Stresses shift peaks then affects structure and texture determination
- d) Combined analysis may be a solution, unless you can destroy your sample or are not interested in macroscopic anisotropy ...
- e) If you think you can destroy it, perhaps think twice
- f) more information is always needed: local probes ...
- g) www.ecole.ensicaen.fr/~chateign/texture/combined.pdf